

# 7MBP100VDN060-50

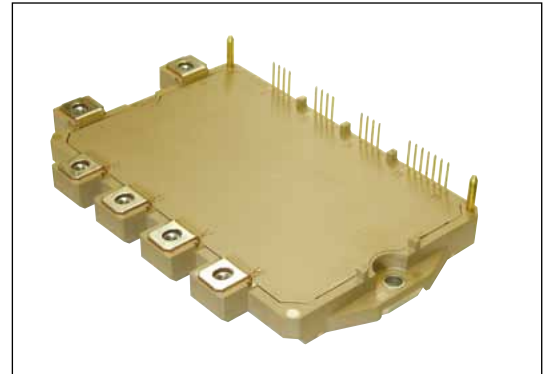
**IGBT Modules**

## IGBT MODULE (V series)

**600V / 100A / IPM**

### ■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ , $V_{cc}=15\text{V}$ unless otherwise specified)

Items		Symbol	Min.	Max.	Units	
Collector-Emitter Voltage (*1)		$V_{CES}$	0	600	V	
Short Circuit Voltage		$V_{SC}$	200	400	V	
Inverter	Collector Current	DC	$I_C$	-	100	A
		1ms	$I_{cp}$	-	200	A
		Duty=94.6% (*2)	$-I_C$	-	100	A
Collector Power Dissipation		1 device (*3)	$P_C$	-	403	W
Brake	Collector Current	DC	$I_C$	-	50	A
		1ms	$I_{cp}$	-	100	A
	Forward Current of Diode		$I_F$	-	50	A
	Collector Power Dissipation		1 device (*3)	$P_C$	-	290
Supply Voltage of Pre-Driver (*4)		$V_{CC}$	-0.5	20	V	
Input Signal Voltage (*5)		$V_{in}$	-0.5	$V_{CC}+0.5$	V	
Alarm Signal Voltage (*6)		$V_{ALM}$	-0.5	$V_{CC}$	V	
Alarm Signal Current (*7)		$I_{ALM}$	-	20	mA	
Junction Temperature		$T_J$	-	150	$^\circ\text{C}$	
Operating Case Temperature		$T_{opr}$	-20	110	$^\circ\text{C}$	
Storage Temperature		$T_{stg}$	-40	125	$^\circ\text{C}$	
Solder Temperature (*8)		$T_{sol}$	-	260	$^\circ\text{C}$	
Isolating Voltage (*9)		$V_{iso}$	-	AC2500	Vrms	
Screw Torque	Terminal (M4)	-	-	1.7	Nm	
	Mounting (M4)	-	-	-	-	

Note \*1:  $V_{CES}$  shall be applied to the input voltage between terminal P-(U,V, W, B) and (U,V, W, B)-N.

Note \*2: Duty=125 $^\circ\text{C}/R_{th(j-c)}$  / ( $I_F \times V_F \text{ Max.}$ )  $\times 100$

Note \*3:  $P_C=125^\circ\text{C}/R_{th(j-c)}$  (Inverter & Brake)

Note \*4:  $V_{CC}$  shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13.

Note \*5:  $V_{in}$  shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 15~18 and 13.

Note \*6:  $V_{ALM}$  shall be applied to the voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 19 and 13.

Note \*7:  $I_{ALM}$  shall be applied to the input current to terminal No.2,6,10 and 19.

Note \*8: Immersion time 10 $\pm$ 1sec. 1time.

Note \*9: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

● Electrical Characteristics ( $T_j=25^\circ\text{C}$ ,  $V_{cc}=15\text{V}$  unless otherwise specified)

Items	Symbol	Conditions	Min.	Typ.	Max.	Units		
Inverter	Collector Current at off signal input	$I_{CES}$	$V_{CE}=600\text{V}$	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=100\text{A}$	Terminal	-	-	2.10	V
				Chip	-	1.45	-	V
	Forward voltage of FWD	$V_F$	$I_F=100\text{A}$	Terminal	-	-	2.40	V
Chip				-	1.80	-	V	
Brake	Collector Current at off signal input	$I_{CES}$	$V_{CE}=600\text{V}$	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=50\text{A}$	Terminal	-	-	1.85	V
				Chip	-	1.40	-	V
	Forward voltage of FWD	$V_F$	$I_F=50\text{A}$	Terminal	-	-	2.60	V
Chip				-	2.15	-	V	
Switching time	$t_{on}$	$V_{bc}=300\text{V}$ , $T_j=125^\circ\text{C}$ , $I_C=100\text{A}$	1.1	-	-	$\mu\text{s}$		
	$t_{off}$		-	-	2.1	$\mu\text{s}$		
	$t_{rr}$	$V_{bc}=300\text{V}$ $I_F=100\text{A}$	-	-	0.3	$\mu\text{s}$		
Supply current of P-side pre-driver (per one unit)	$I_{ccp}$	Switching Frequency= 0-15kHz $T_c=-20\sim 110^\circ\text{C}$	-	-	15	mA		
Supply current of N-side pre-driver	$I_{ccn}$		-	-	60	mA		
Input signal threshold voltage	$V_{in(th)(on)}$	$V_{in}\text{-GND}$	ON	1.2	1.4	1.6	V	
	$V_{in(th)(off)}$		OFF	1.5	1.7	1.9	V	
Over Current Protection Level	Inverter Brake	$I_{OC}$	$T_j=125^\circ\text{C}$	150	-	-	A	
				75	-	-	A	
Over Current Protection Delay time	$t_{dOC}$	$T_j=125^\circ\text{C}$	-	5	-	$\mu\text{s}$		
Short Circuit Protection Delay time	$t_{sc}$	$T_j=125^\circ\text{C}$	-	2	3	$\mu\text{s}$		
IGBT Chips Over Heating Protection Temperature Level	$T_{jOH}$	Surface of IGBT Chips	150	-	-	$^\circ\text{C}$		
Over Heating Protection Hysteresis	$T_{jH}$		-	20	-	$^\circ\text{C}$		
Under Voltage Protection Level	$V_{UV}$		11.0	-	12.5	V		
Under Voltage Protection Hysteresis	$V_H$		0.2	0.5	-	V		
Alarm Signal Hold Time	$t_{ALM(OC)}$	ALM-GND $T_c=-20\sim 110^\circ\text{C}$	$V_{cc} \geq 10\text{V}$	1.0	2.0	2.4	ms	
	$t_{ALM(UV)}$			2.5	4.0	4.9	ms	
	$t_{ALM(TjOH)}$			5.0	8.0	11.0	ms	
Resistance for current limit	$R_{ALM}$		960	1265	1570	$\Omega$		

● Thermal Characteristics ( $T_c = 25^\circ\text{C}$ )

Items		Symbol	Min.	Typ.	Max.	Units	
Junction to Case Thermal Resistance (*10)	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.31	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	0.55	$^\circ\text{C}/\text{W}$
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	0.43	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	0.99	$^\circ\text{C}/\text{W}$
Case to Fin Thermal Resistance with Compound		$R_{th(c-f)}$	-	0.05	-	$^\circ\text{C}/\text{W}$	

Note \*10: For 1device, the measurement point of the case is just under the chip.

● Noise Immunity ( $V_{bc}=300\text{V}$ ,  $V_{cc}=15\text{V}$ )

Items	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width $1\mu\text{s}$ , polarity $\pm$ , 10 min. Judge : no over-current, no miss operating	$\pm 2.0$	-	-	kV

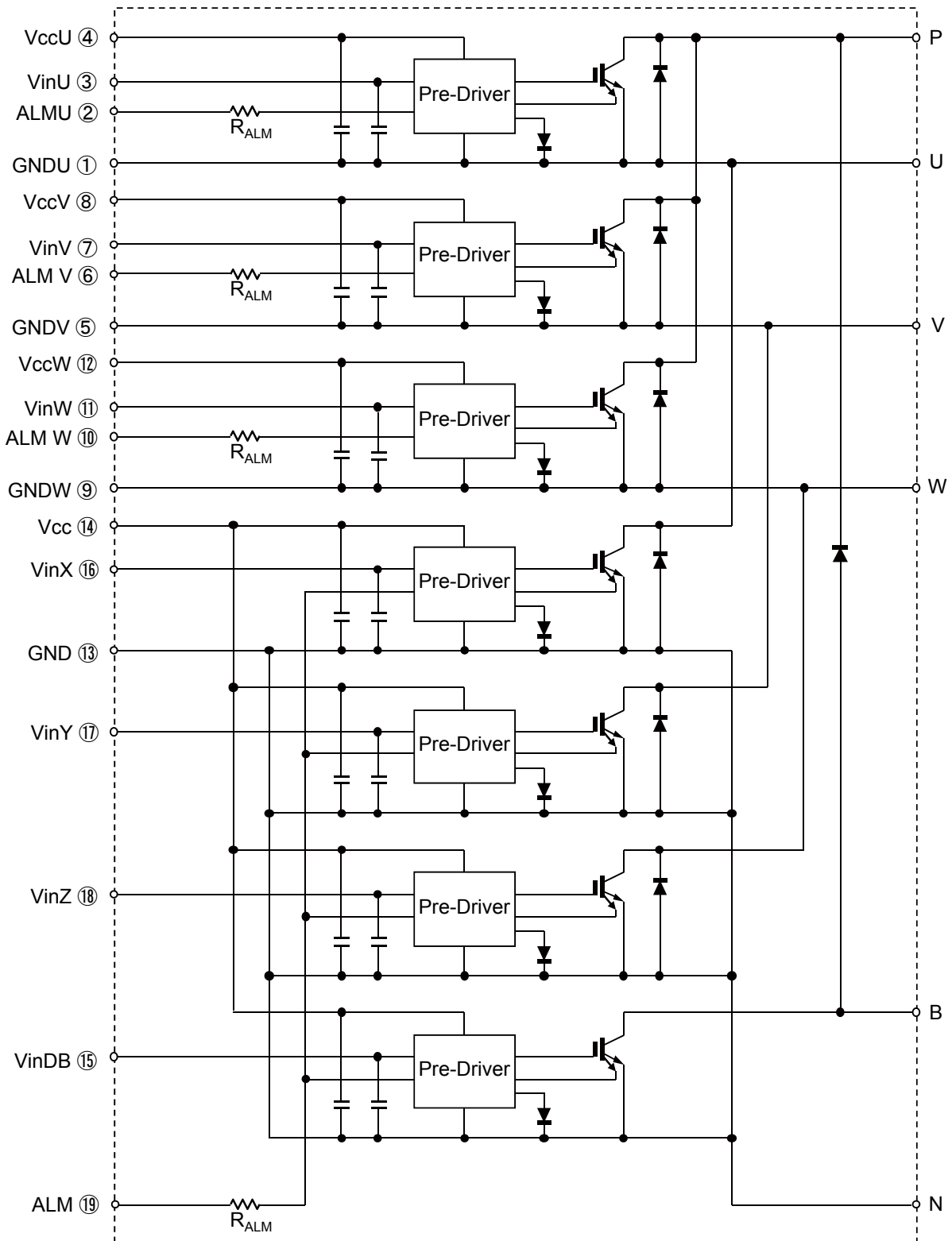
● Recommended Operating Conditions

Items	Symbol	Min.	Typ.	Max.	Units
DC Bus Voltage	$V_{DC}$	-	-	400	V
Power Supply Voltage of Pre-Driver	$V_{CC}$	13.5	15.0	16.5	V
Switching frequency of IPM	$f_{sw}$	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	$t_{dead}$	1.0	-	-	$\mu\text{s}$
Screw Torque (M4)	-	1.3	-	1.7	Nm

● Weight

Items	Symbol	Min.	Typ.	Max.	Units
Weight	$W_t$	-	290	-	g

■ Block Diagram

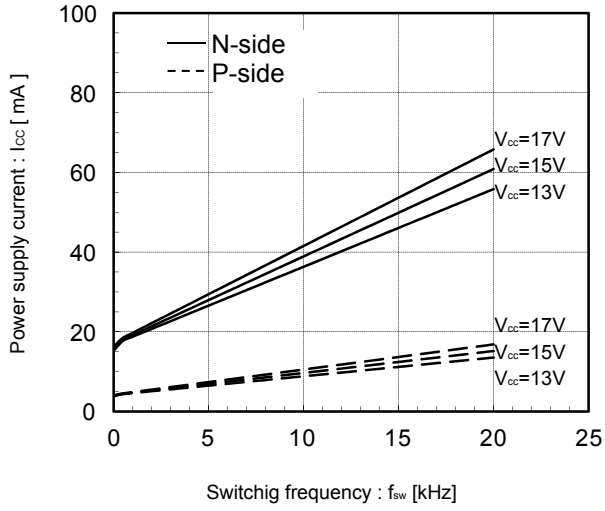


Pre-drivers include following functions

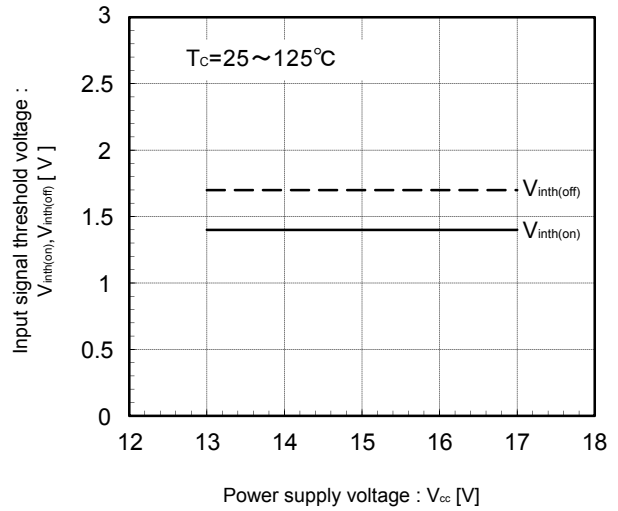
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

■ Characteristics (Representative)

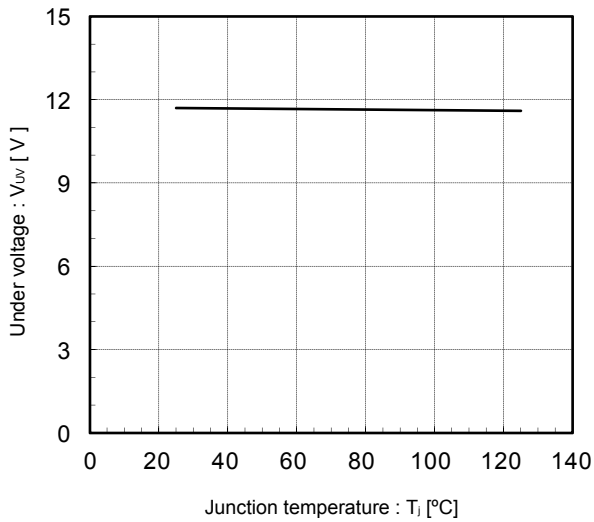
Power supply current vs. Switching frequency  
 $T_J=25^\circ\text{C}$  (typ.)



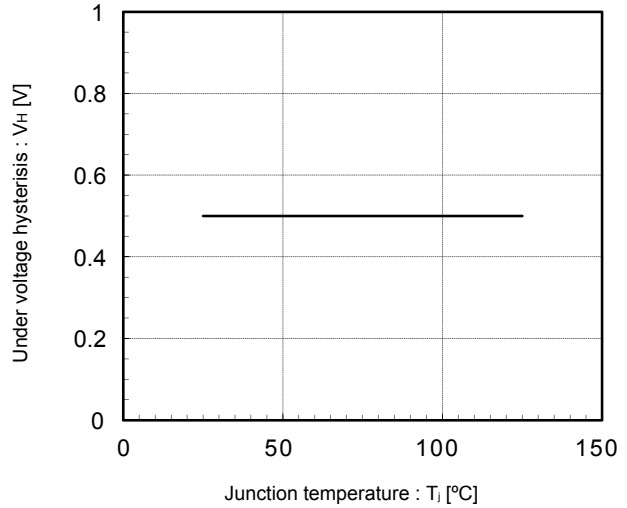
Input signal threshold voltage vs. Power supply voltage (typ.)



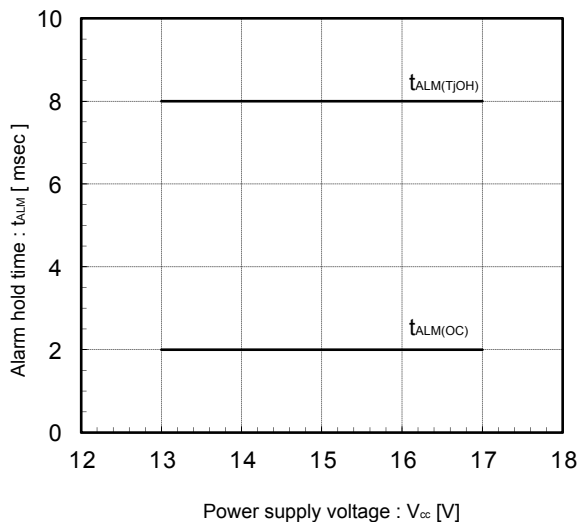
Under voltage vs. Junction temperature (typ.)



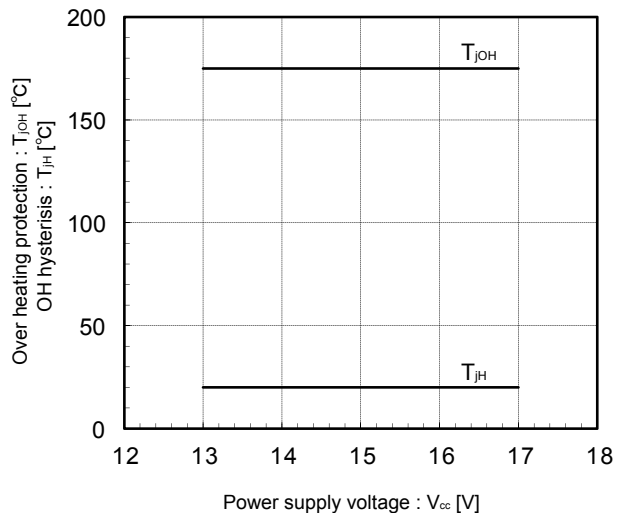
Under voltage hysteresis vs. Junction temperature (typ.)



Alarm hold time vs. Power supply voltage (typ.)

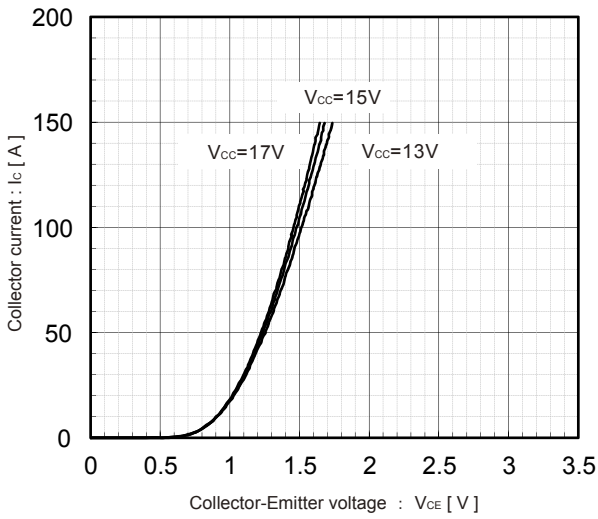


Over heating characteristics  
 $T_{JOH}, T_{JH}$  vs.  $V_{CC}$  (typ.)

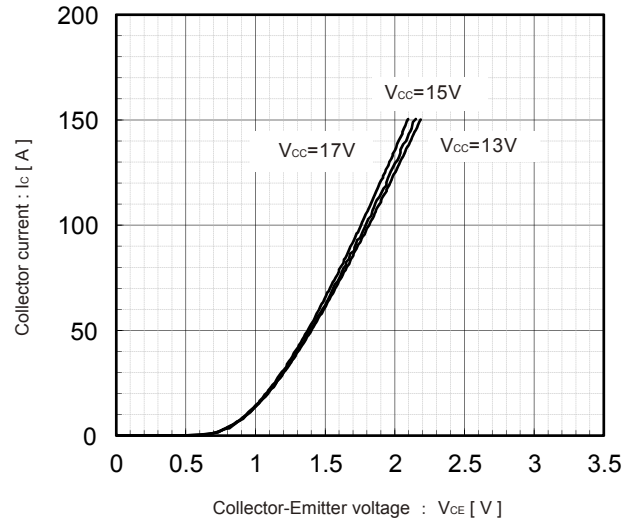


Inverter

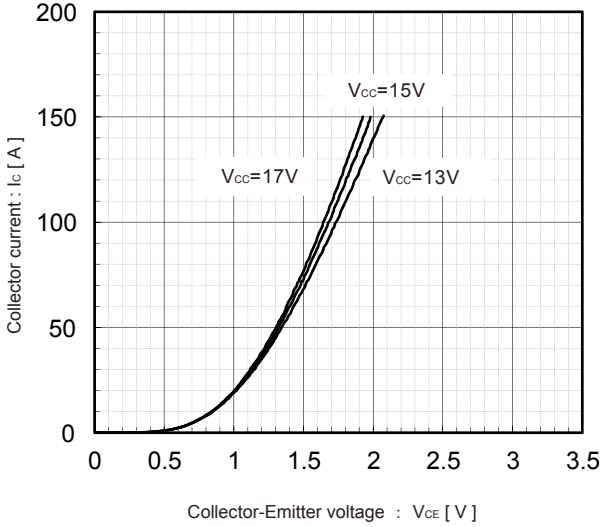
Collector current vs. Collector-Emitter voltage  
 $T_j=25^\circ\text{C}$ [Chip] (typ.)



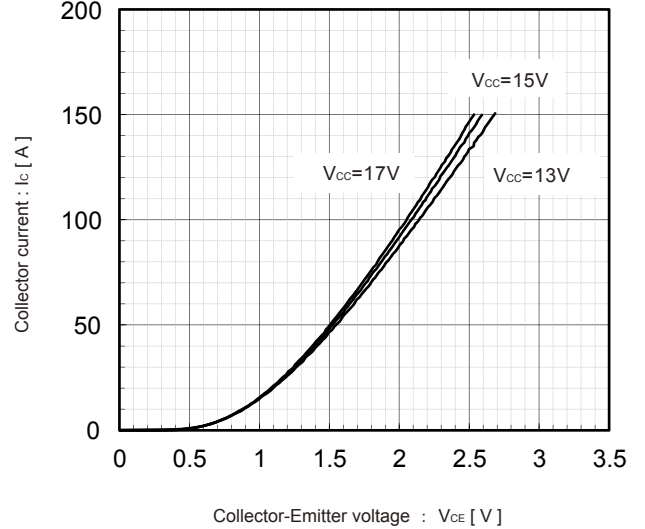
Collector current vs. Collector-Emitter voltage  
 $T_j=25^\circ\text{C}$ [Terminal] (typ.)



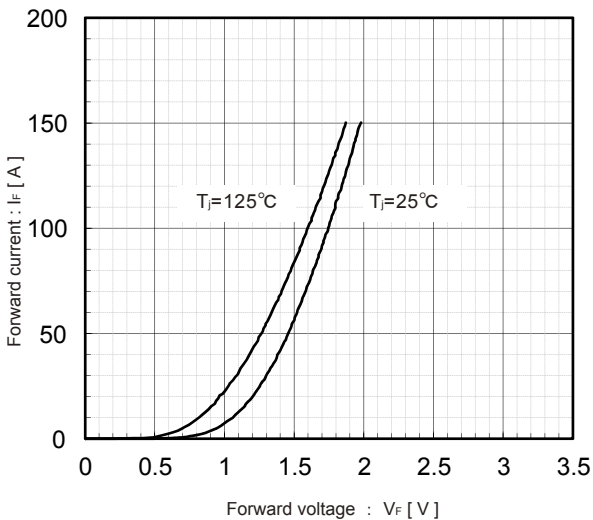
Collector current vs. Collector-Emitter voltage  
 $T_j=125^\circ\text{C}$ [Chip] (typ.)



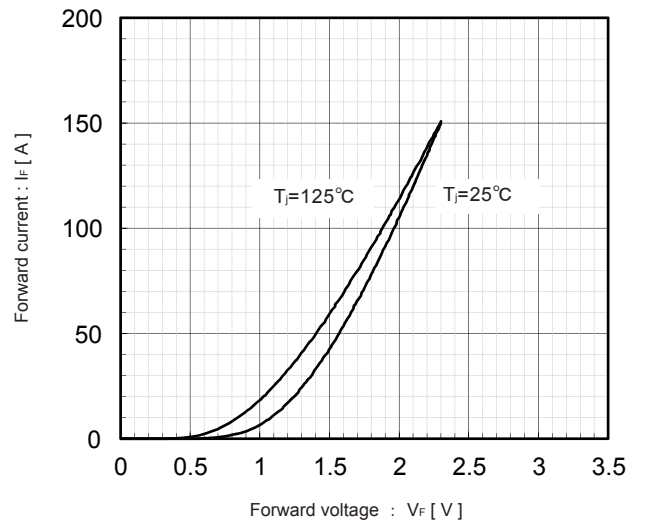
Collector current vs. Collector-Emitter voltage  
 $T_j=125^\circ\text{C}$ [Terminal] (typ.)



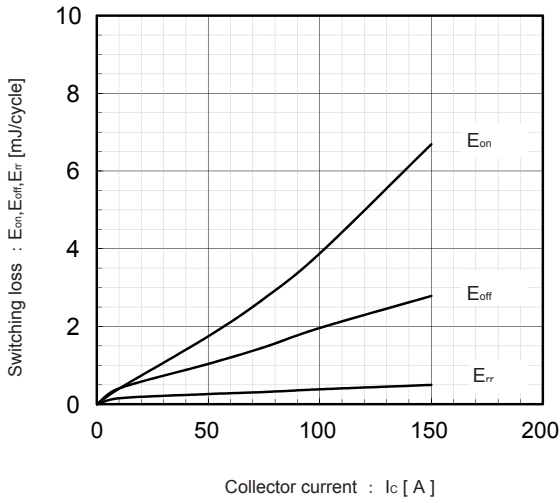
Forward current vs. Forward voltage  
 [Chip] (typ.)



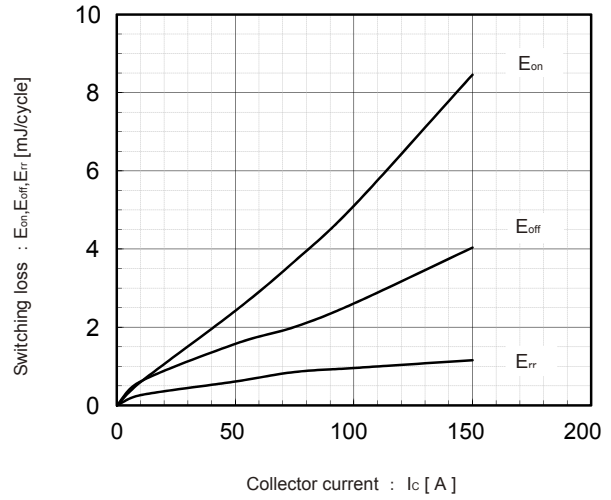
Forward current vs. Forward voltage  
 [Terminal] (typ.)



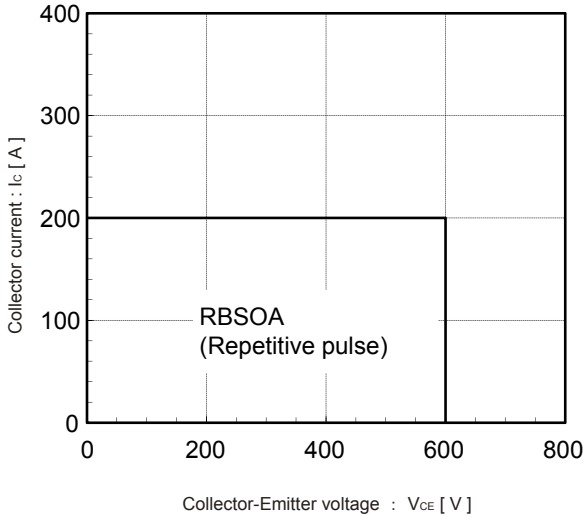
Switching Loss vs. Collector Current (typ.)  
 $V_{dc}=300V, V_{cc}=15V, T_j=25^\circ C$



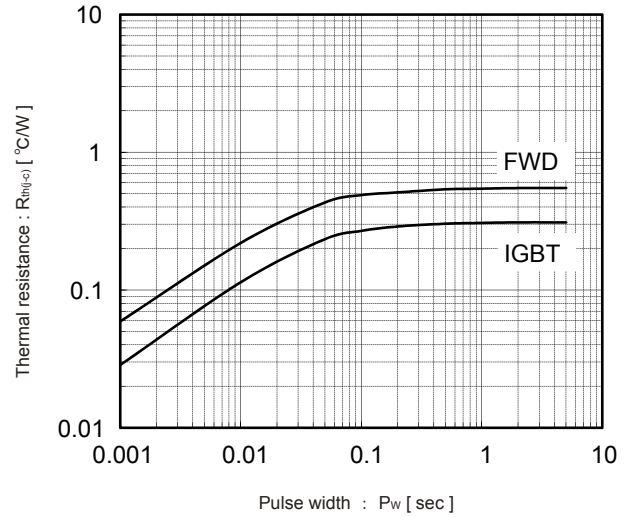
Switching Loss vs. Collector Current (typ.)  
 $V_{dc}=300V, V_{cc}=15V, T_j=125^\circ C$



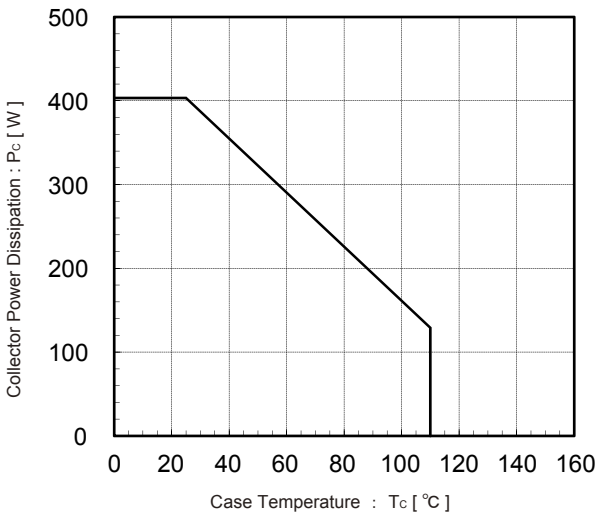
Reversed biased safe operating area  
 $V_{cc}=15V, T_j \le 125^\circ C$



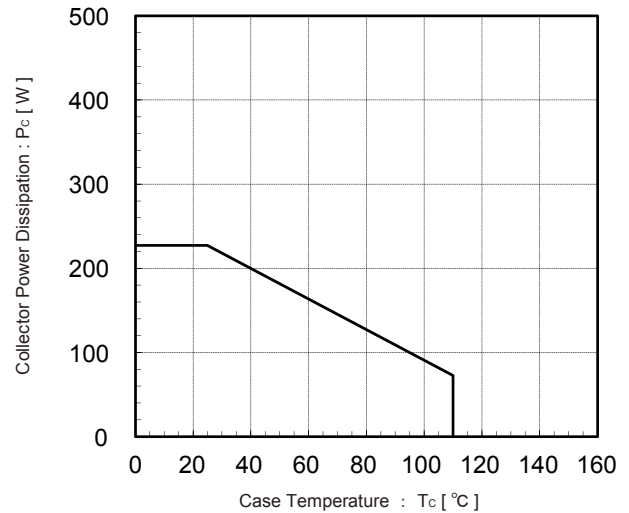
Transient thermal resistance (max.)



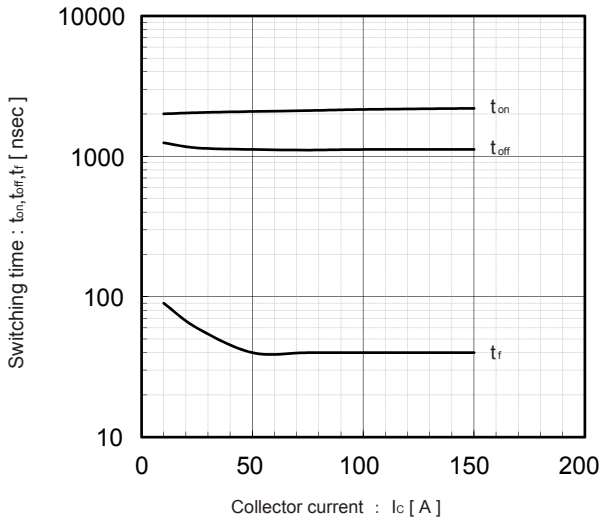
Power derating for IGBT (max.)  
 [per device]



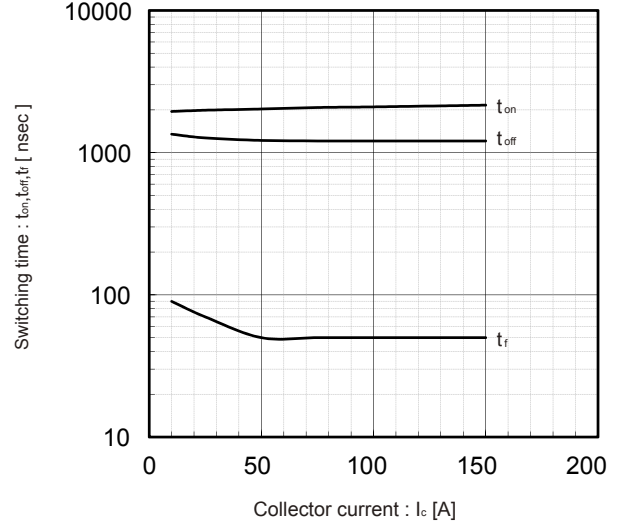
Power derating for FWD (max.)  
 [per device]



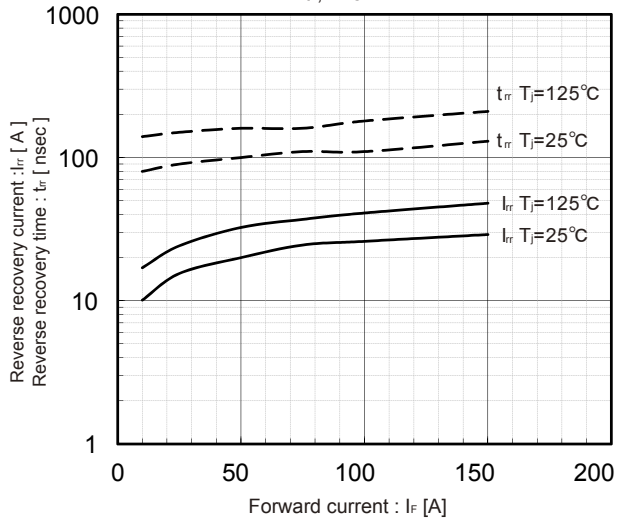
Switching time vs. Collector current (typ.)  
 $V_{DC}=300V, V_{CC}=15V, T_J=25^\circ C$



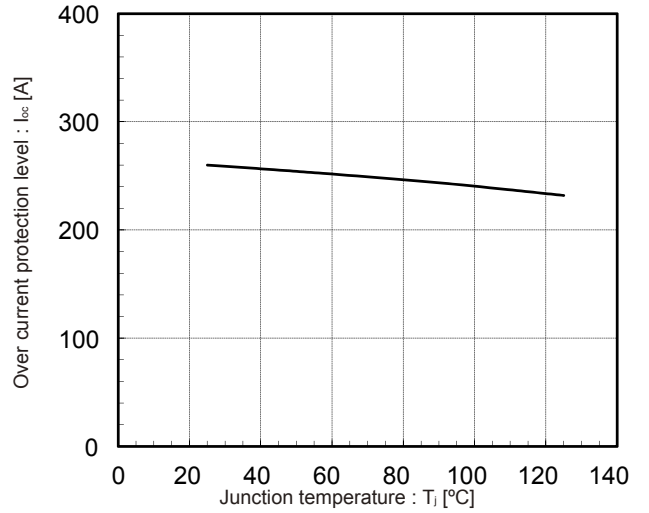
Switching time vs. Collector current (typ.)  
 $V_{DC}=300V, V_{CC}=15V, T_J=125^\circ C$



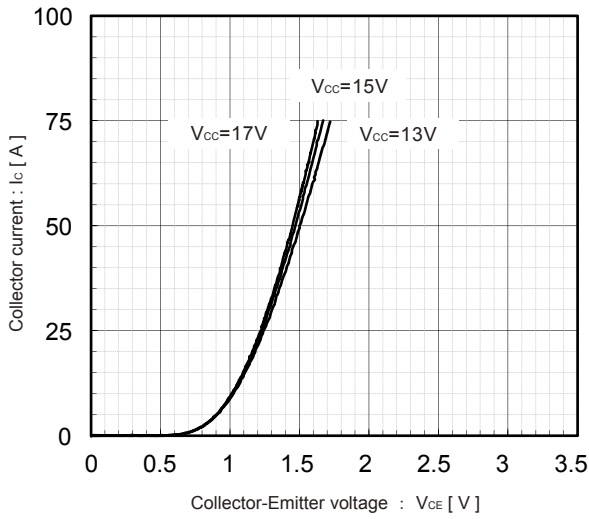
Reverse recovery characteristics (typ.)  
 $t_{rr}, I_{rr}$  vs.  $I_F$



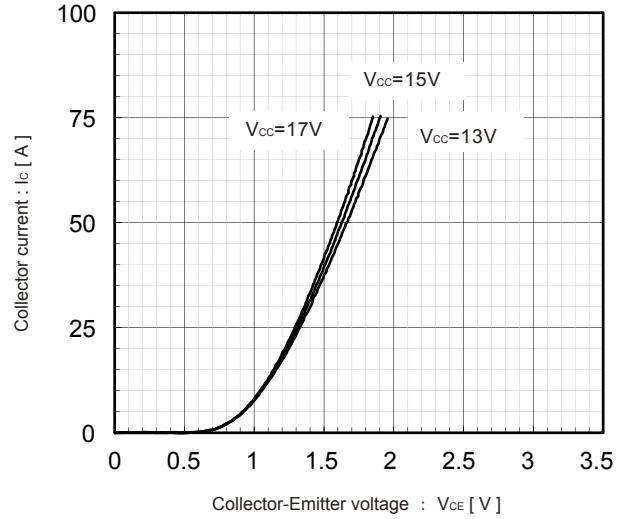
Over current protection vs. Junction temperature (typ.)  $V_{CC}=15V$



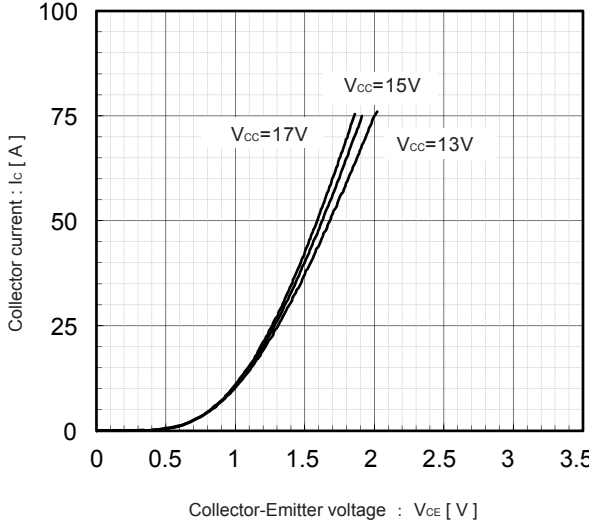
Collector current vs. Collector-Emmitter voltage  
 $T_j=25^\circ\text{C}$ [Chip] (typ.)



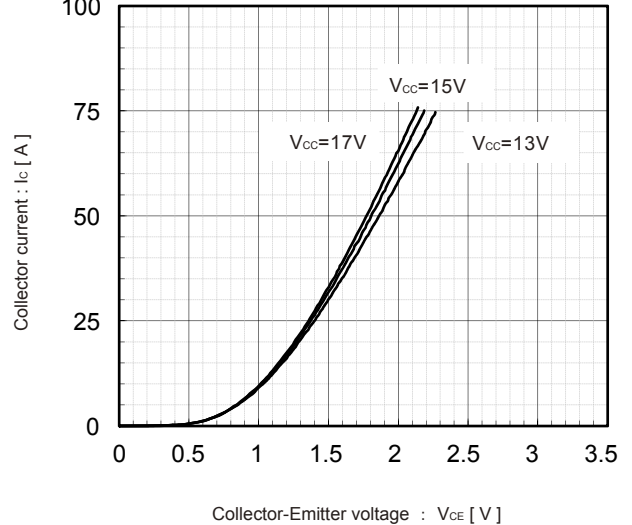
Collector current vs. Collector-Emmitter voltage  
 $T_j=25^\circ\text{C}$ [Terminal] (typ.)



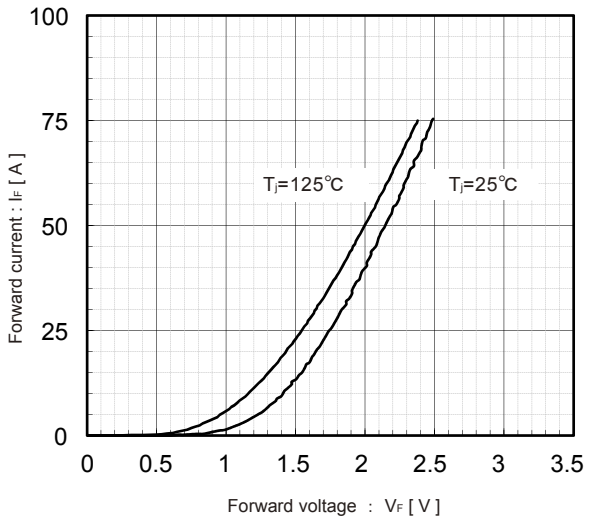
Collector current vs. Collector-Emmitter voltage  
 $T_j=125^\circ\text{C}$ [Chip] (typ.)



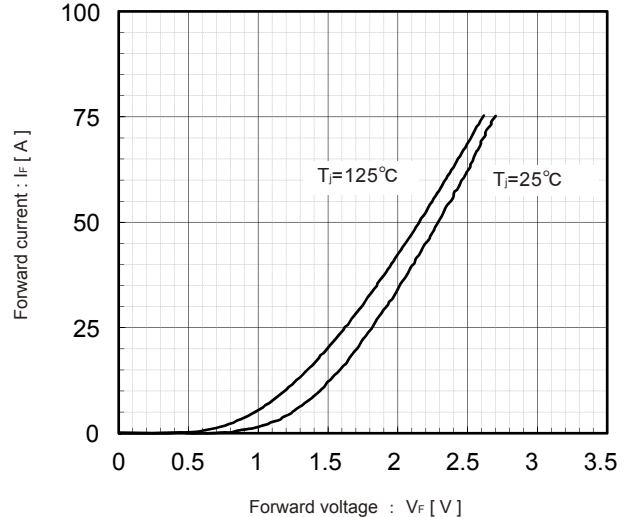
Collector current vs. Collector-Emmitter voltage  
 $T_j=125^\circ\text{C}$ [Terminal] (typ.)



Forward current vs. Forward voltage  
 [Chip] (typ.)

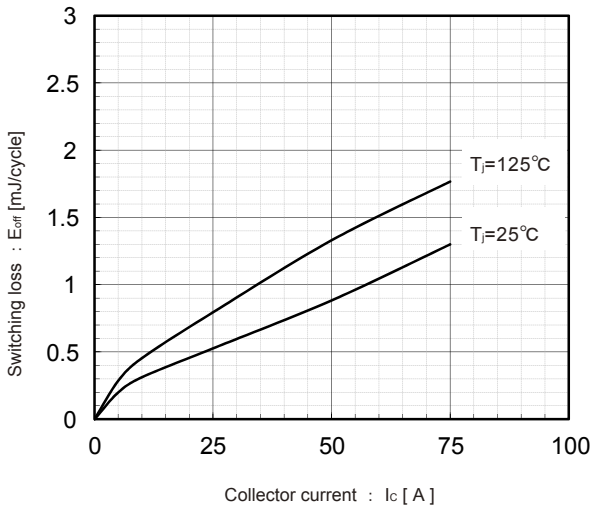


Forward current vs. Forward voltage  
 [Terminal] (typ.)

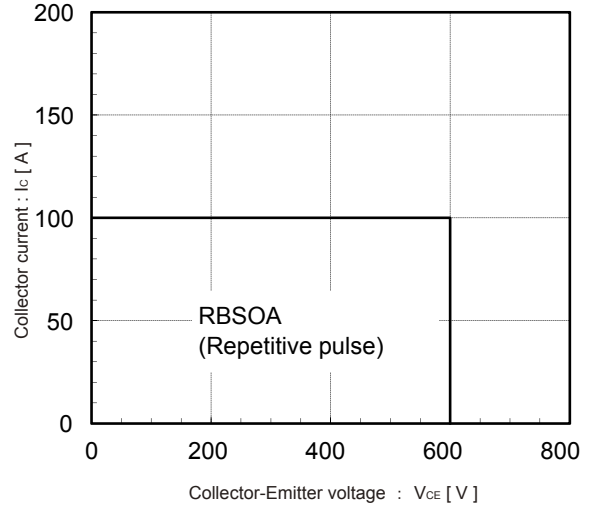




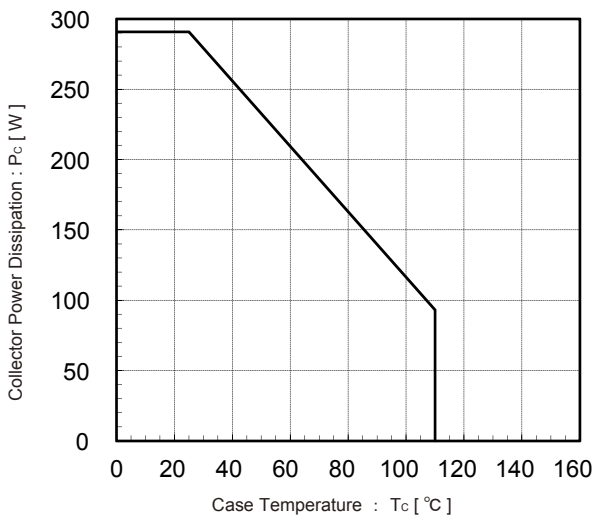
Switching Loss vs. Collector Current (typ.)  
 $V_{bc}=300V, V_{cc}=15V$



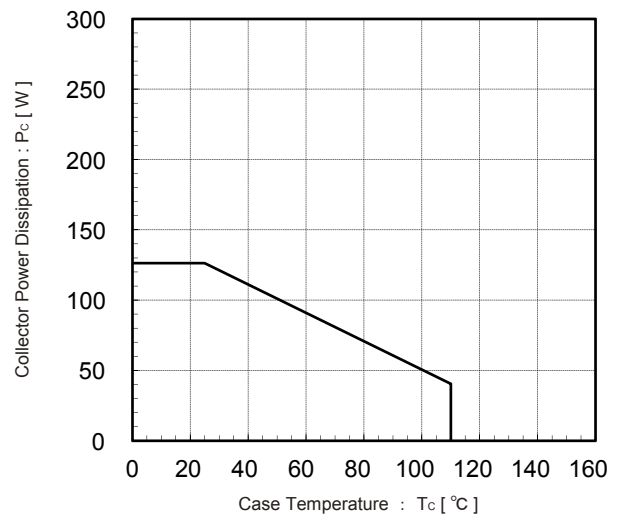
Reversed biased safe operating area  
 $V_{cc}=15V, T_j \le 125^\circ C$  [Main Terminal] (min.)



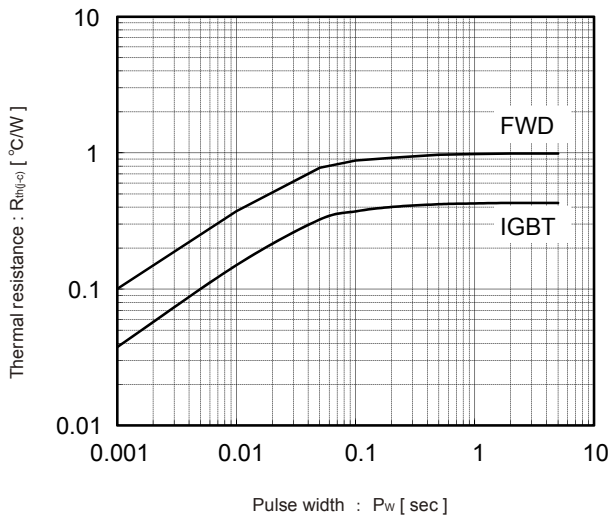
Power derating for IGBT (max.)  
 [per device]



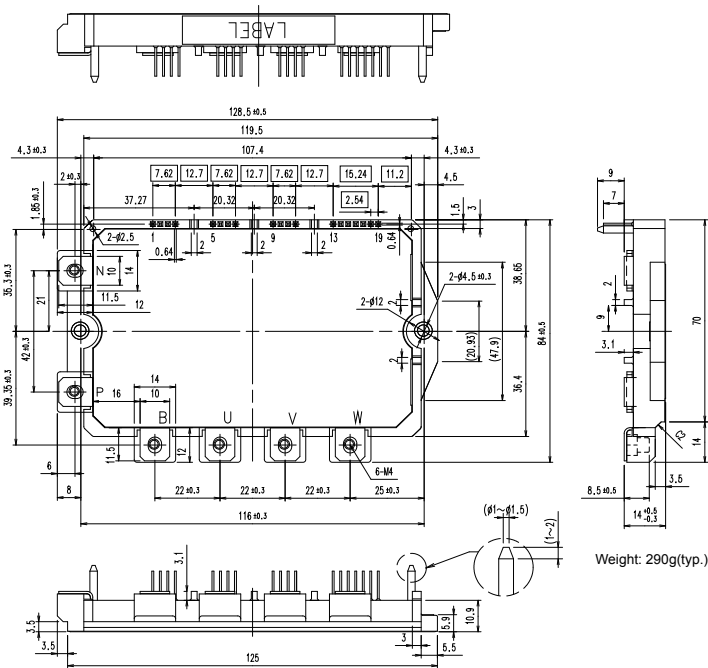
Power derating for FWD (max.)  
 [per device]



Transient thermal resistance (max.)



■ Outline Drawings, mm



**WARNING**

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  - OA equipment
  - Communications equipment (terminal devices)
  - Measurement equipment
  - Machine tools
  - Audiovisual equipment
  - Electrical home appliances
  - Personal equipment
  - Industrial robots etc.
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  - Trunk communications equipment
  - Traffic-signal control equipment
  - Gas leakage detectors with an auto-shut-off feature
  - Emergency equipment for responding to disasters and anti-burglary devices
  - Safety devices
  - Medical equipment
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  - Aeronautic equipment
  - Nuclear control equipment
  - Submarine repeater equipment
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**IGBT Modules**

- Please refer to URLs below for further information about products, application manuals and technical documents.
- 关于本规格书中没有记载的产品信息·应用手册·技术资料等·请参考以下链接。
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## FUJI ELECTRIC Power Semiconductor WEB site

日本	<a href="http://www.fujielectric.co.jp/products/semiconductor/">www.fujielectric.co.jp/products/semiconductor/</a>
Global	<a href="http://www.fujielectric.com/products/semiconductor/">www.fujielectric.com/products/semiconductor/</a>
中国	<a href="http://www.fujielectric.com.cn/products/semiconductor/">www.fujielectric.com.cn/products/semiconductor/</a>
Europe	<a href="http://www.fujielectric-europe.com/components/semiconductors/">www.fujielectric-europe.com/components/semiconductors/</a>
North America	<a href="http://www.americas.fujielectric.com/components/semiconductors/">www.americas.fujielectric.com/components/semiconductors/</a>

## Information

### 日本

1 半導体総合カタログ	<a href="http://www.fujielectric.co.jp/products/semiconductor/catalog/">www.fujielectric.co.jp/products/semiconductor/catalog/</a>
2 製品情報	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/">www.fujielectric.co.jp/products/semiconductor/model/</a>
3 アプリケーションマニュアル	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/application/">www.fujielectric.co.jp/products/semiconductor/model/igbt/application/</a>
4 技術資料	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/">www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/</a>
5 マウンティングインストラクション	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/">www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 損失シミュレーションソフト	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/">www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level 損失シミュレーションソフト	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation_3level/</a>
8 富士電機技報	<a href="http://www.fujielectric.co.jp/products/semiconductor/journal/">www.fujielectric.co.jp/products/semiconductor/journal/</a>
9 製品のお問い合わせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/contact/">www.fujielectric.co.jp/products/semiconductor/contact/</a>
10 改廃のお知らせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/discontinued/">www.fujielectric.co.jp/products/semiconductor/discontinued/</a>

### Global

1 Semiconductors General Catalog	<a href="http://www.fujielectric.com/products/semiconductor/catalog/">www.fujielectric.com/products/semiconductor/catalog/</a>
2 Product Information	<a href="http://www.fujielectric.com/products/semiconductor/model/">www.fujielectric.com/products/semiconductor/model/</a>
3 Application Manuals	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/application/">www.fujielectric.com/products/semiconductor/model/igbt/application/</a>
4 Technical Documents	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/technical/">www.fujielectric.com/products/semiconductor/model/igbt/technical/</a>
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6 IGBT Loss Simulation Software	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/simulation/">www.fujielectric.com/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level Loss Simulation Software	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.com/products/semiconductor/model/igbt/simulation_3level/</a>
8 Fuji Electric Journal	<a href="http://www.fujielectric.com/products/semiconductor/journal/">www.fujielectric.com/products/semiconductor/journal/</a>
9 Contact	<a href="http://www.fujielectric.com/products/semiconductor/contact/">www.fujielectric.com/products/semiconductor/contact/</a>
10 Revised and discontinued product information	<a href="http://www.fujielectric.com/products/semiconductor/discontinued/">www.fujielectric.com/products/semiconductor/discontinued/</a>

### 中国

1 半导体综合目录	<a href="http://www.fujielectric.com.cn/products/semiconductor/catalog/">www.fujielectric.com.cn/products/semiconductor/catalog/</a>
2 产品信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/">www.fujielectric.com.cn/products/semiconductor/model/</a>
3 应用手册	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/application/">www.fujielectric.com.cn/products/semiconductor/model/igbt/application/</a>
4 技术资料	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/">www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/</a>
5 安装说明书	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/">www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/</a>
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9 产品咨询	<a href="http://www.fujielectric.com.cn/products/semiconductor/contact/">www.fujielectric.com.cn/products/semiconductor/contact/</a>
10 产品更改和停产信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/discontinued/">www.fujielectric.com.cn/products/semiconductor/discontinued/</a>